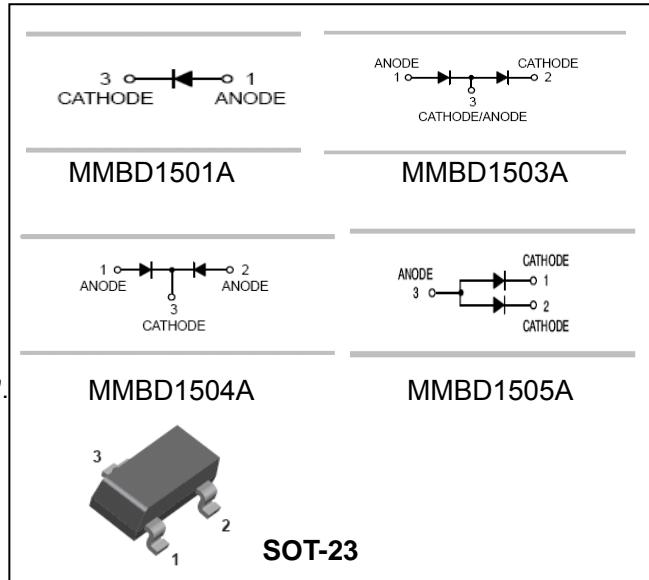


High conductance low leakage diode

**MMBD1501A/1503A/
1504A/1505A**

FEATURES

- Two element incorporated into one package.
(Emitter-coupled transistors)
- Reduction of the mounting area and assembly cost by one half.
- RoHS product for packing code suffix "G", Halogen free product for packing code suffix "H".
- **Moisture Sensitivity Level 1**



APPLICATIONS

- For general application.

ORDERING INFORMATION

Type No.	Marking	Package Code
MMBD1501A	A11	SOT-23
MMBD1503A	A13	SOT-23
MMBD1504A	A14	SOT-23
MMBD1505A	A15	SOT-23

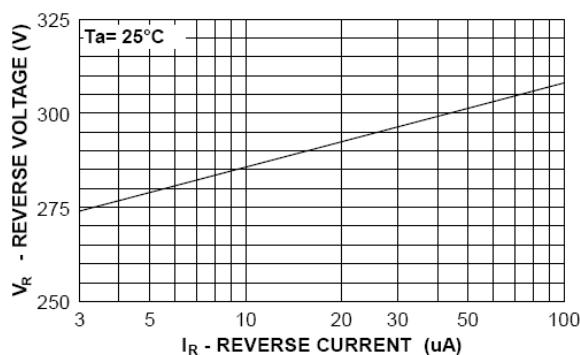
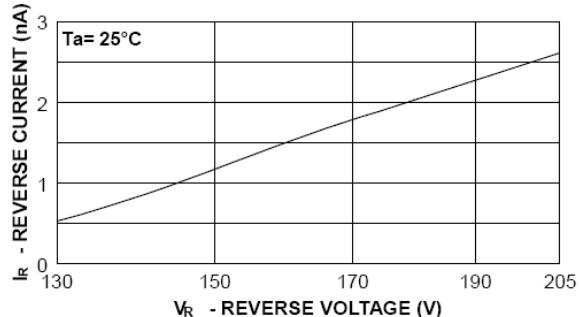
MAXIMUM RATING @ Ta=25°C unless otherwise specified

Parameter	Symbol	Limits	Unit
Reverse Voltage	V _R	200	V
Average rectified current	V _{F(AV)}	200	mA
Forward Continuous Current	I _{FM}	700	mA
Peak forward current (1.0s) (1.0m)	I _{FSM}	1.0 2.0	A
Power Dissipation	P _d	350	mW
Thermal resistance, Junction to ambient	R _{θJA}	357	°C/W
Storage temperature	T _{STG}	-55-150	°C

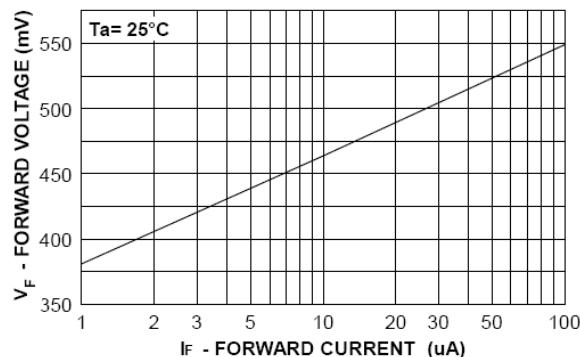
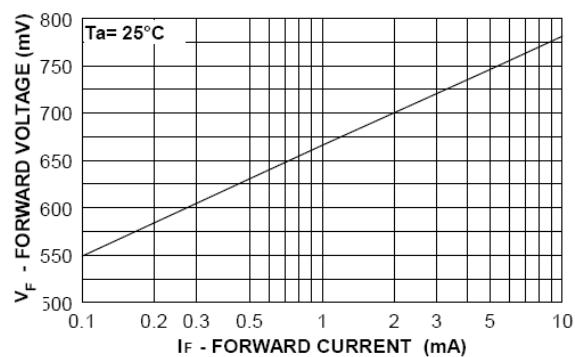
High conductance low leakage diode

**MMBD1501A/1503A/
1504A/1505A**
ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

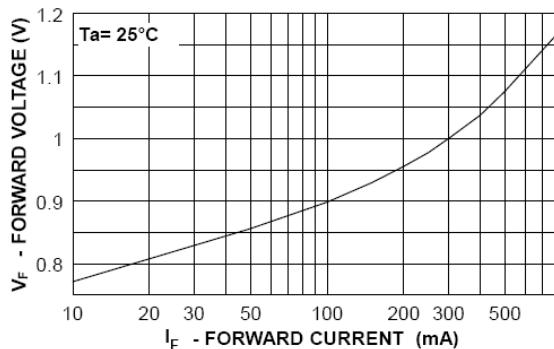
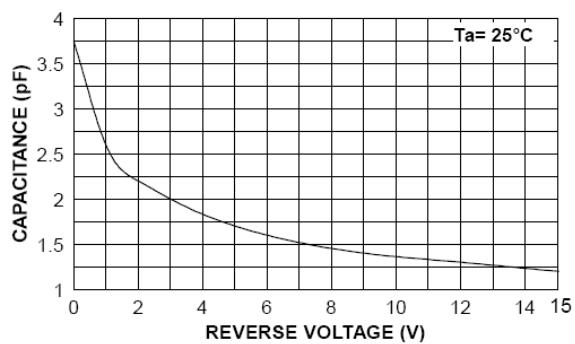
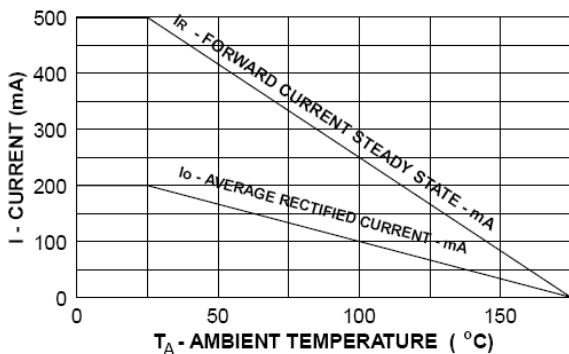
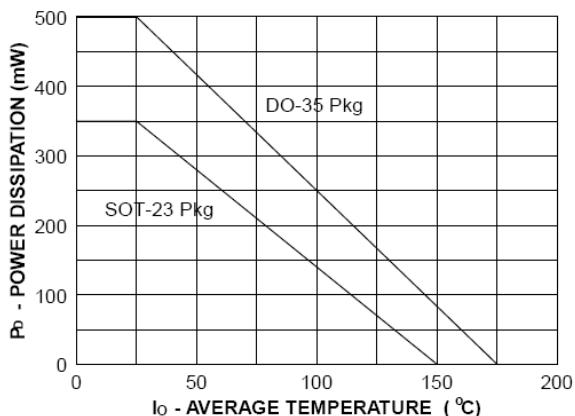
Parameter	Symbol	Min.	Max.	Unit	Test Conditions
Reverse Breakdown Voltage	$V_{(BR)R1}$	200		V	$I_R=5\mu A$
Forward voltage	V_F		V	0.75	$I_F=1mA$
				0.85	$I_F=10mA$
				0.95	$I_F=50mA$
				1.1	$I_F=100mA$
				1.3	$I_F=200mA$
				1.50	$I_F=300mA$
Reverse current	I_R		1.0 10	nA	$V_R=125V$ $V_R=180V$
Diode Capacitance	C_D		4	pF	$V_R=0V, f=1MHz$

TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified
REVERSE VOLTAGE vs REVERSE CURRENT
BV - 3.0 to 100 uA

REVERSE CURRENT vs REVERSE VOLTAGE
IR - 130 - 205 Volts


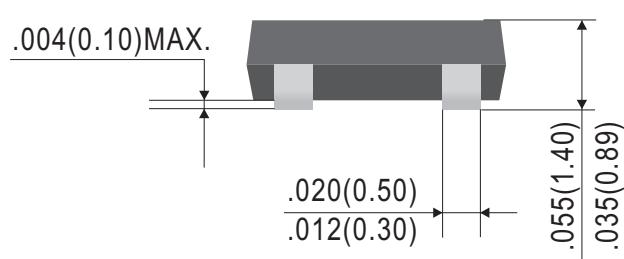
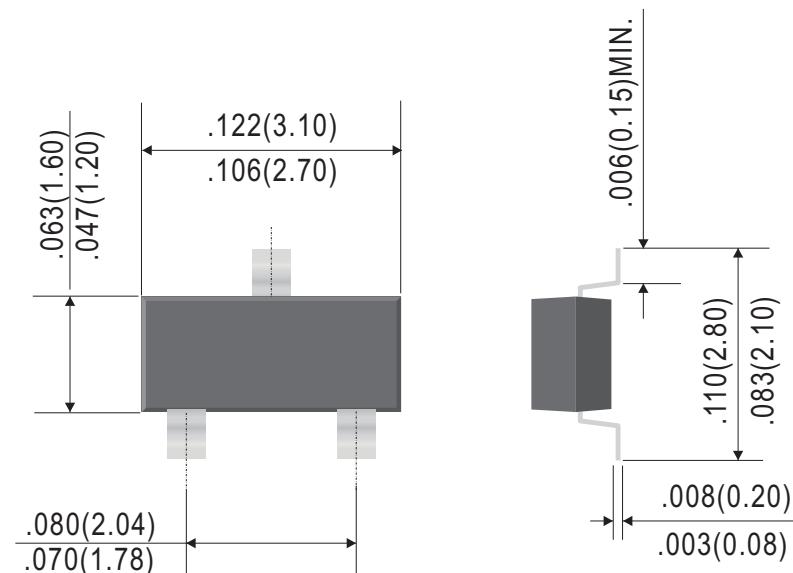
GENERAL RULE: The Reverse Current of a diode will approximately double for every ten (10) Degree C increase in Temperature

FORWARD VOLTAGE vs FORWARD CURRENT
VF - 1 to 100 uA

FORWARD VOLTAGE vs FORWARD CURRENT
VF - 0.1 to 10 mA


High conductance low leakage diode

**MMBD1501A/1503A/
1504A/1505A****FORWARD VOLTAGE vs FORWARD CURRENT**
VF - 10 to 800 mA**CAPACITANCE vs REVERSE VOLTAGE**
VR - 0 to 15 V**Average Rectified Current (I_o) &
Forward Current (I_F) versus
Ambient Temperature (T_A)****POWER DERATING CURVE**

High conductance low leakage diode

**MMBD1501A/1503A/
1504A/1505A**
SOT-23


Dimensions in inches and (millimeters)

PACKAGE INFORMATION

Device	Package	Shipping
MMBD1501A/1503A/1504A/1505A	SOT-23	3000/Tape&Reel